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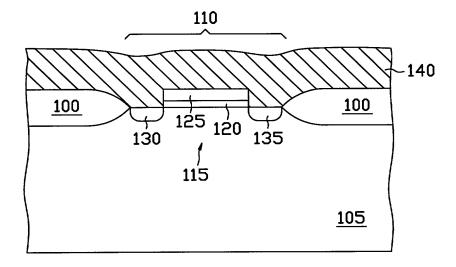


FIG. 1

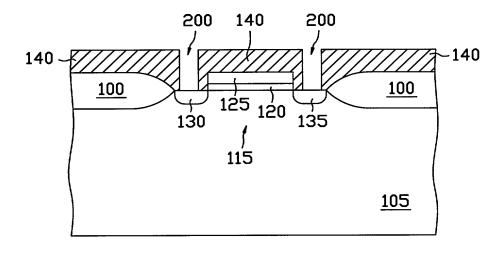


FIG. 2

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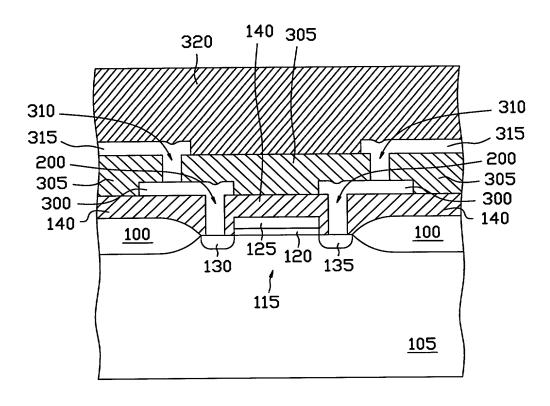
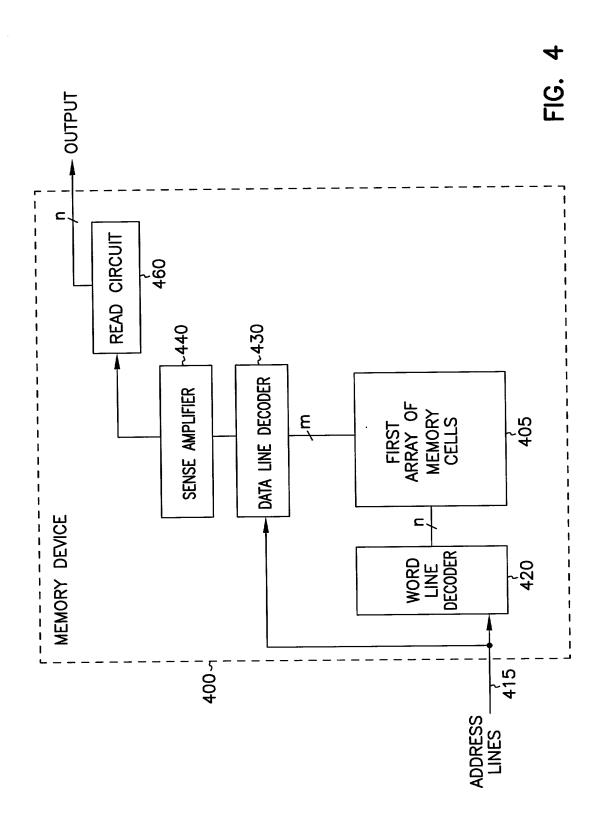


FIG. 3



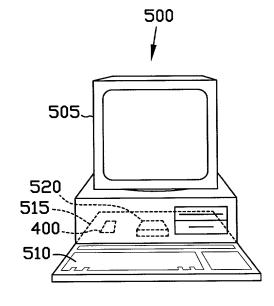


FIG. 5